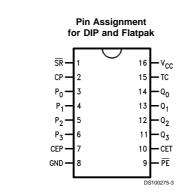


54AC163 • 54ACT163 Synchronous Presettable Binary Counter

## **Connection Diagrams**



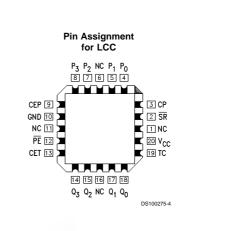
### **Functional Description**

The 'AC/'ACT163 counts in modulo-16 binary sequence. From state 15 (HHHH) it increments to state 0 (LLLL). The clock inputs of all flip-flops are driven in parallel through a clock buffer. Thus all changes of the Q outputs occur as a result of, and synchronous with, the LOW-to-HIGH transition of the CP input signal. The circuits have four fundamental modes of operation, in order of precedence: synchronous reset, parallel load, count-up and hold, Four control inputs — Synchronous Reset (SR), Parallel Enable (PE), Four control Count Enable Parallel (CEP) and Count Enable Trickle (CET) - determine the mode of operation, as shown in the Mode Select Table. A LOW signal on SR overrides counting and parallel loading and allows all outputs to go LOW on the next rising edge of CP. A LOW signal on PE overrides counting and allows information on the Parallel Data (Pn) inputs to be loaded into the flip-flops on the next rising edge of CP. With PE and SR HIGH, CEP and CET permit counting when both are HIGH. Conversely, a LOW signal on either CEP or CET inhibits counting.

The 'AC/'ACT163 uses D-type edge-triggered flip-flops and changing the  $\overline{SR}$ ,  $\overline{PE}$ , CEP and CET inputs when the CP is in either state does not cause errors, provided that the recommended setup and hold times, with respect to the rising edge of CP, are observed.

The Terminal Count (TC) output is HIGH when CET is HIGH and counter is in state 15. To implement synchronous multistage counters, the TC outputs can be used with the CEP and CET inputs in two different ways.

Figure 1 shows the connections for simple ripple carry, in which the clock period must be longer than the CP to  $\overline{TC}$  delay of the first stage, plus the cumulative  $\overline{CET}$  to  $\overline{TC}$  delays of the intermediate stages, plus the  $\overline{CET}$  to  $\overline{TC}$  delays of the last stage. This total delay plus setup time sets the upper limit on clock frequency. For faster clock rates, the carry lookahead connections shown in *Figure 2* are recommended. In this scheme the ripple delay through the intermediate stages commences with the same clock that causes the first stage to tick over from max to min in the Up mode, or min to max in the Down mode, to start its final cycle. Since this final cycle takes 16 clocks to complete, there is plenty of time for the ripple to progress through the intermediate stages. The critical timing that limits the clock period is the CP to  $\overline{TC}$  de-



lay of the first stage plus the  $\overline{CEP}$  to CP setup time of the last stage. The  $\overline{TC}$  output is subject to decoding spikes due to internal race conditions and is therefore not recommended for use as a clock or asynchronous reset for flip-flops, registers or counters.

Logic Equations: Count Enable = CEP • CET •  $\overline{PE}$ TC = Q<sub>0</sub> • Q<sub>1</sub> • Q<sub>2</sub> • Q<sub>3</sub> • CET

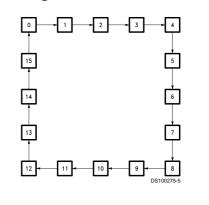
## **Mode Select Table**

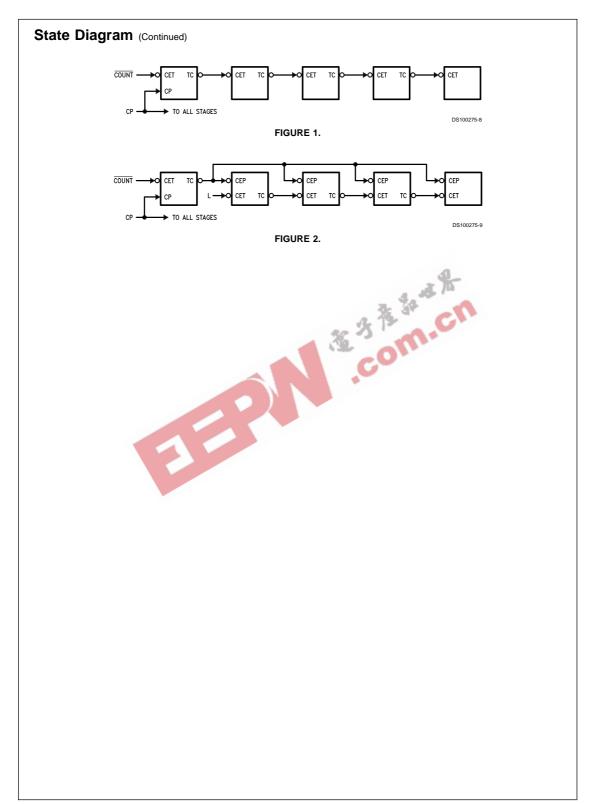
SR	PE	CET	CEP	Action on the Rising
				Clock Edge (-/-)
L	Х	Х	Х	Reset (Clear)
н	L	Х	Х	Load $(P_n \rightarrow Q_n)$
н	н	н	н	Count (Increment)
н	н	L	Х	No Change (Hold)
н	н	Х	L	No Change (Hold)

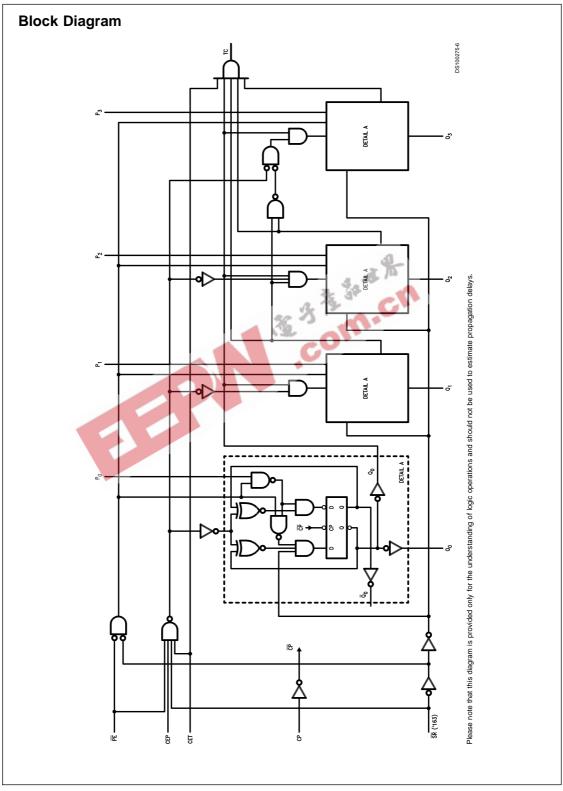
H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial

## State Diagram







4

Absolute Maximum R If Military/Aerospace specified please contact the National Semi Distributors for availability and s	devices are required, conductor Sales Office/
Supply Voltage (V <sub>CC</sub> )	-0.5V to +7.0V
DC Input Diode Current (IIK)	
$V_{1} = -0.5V$	–20 mA
$V_{I} = V_{CC} + 0.5V$	+20 mA
DC Input Voltage (VI)	–0.5V to V <sub>CC</sub> + 0.5V
DC Output Diode Current (I <sub>OK</sub> )	
$V_{O} = -0.5V$	–20 mA
$V_{O} = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V <sub>O</sub> )	-0.5V to V <sub>CC</sub> + 0.5V
DC Output Source	
or Sink Current (I <sub>O</sub> )	±50 mA
DC V <sub>CC</sub> or Ground Current	
per Output Pin (I <sub>CC</sub> or I <sub>GND</sub> )	±50 mA
Storage Temperature (T <sub>STG</sub> )	-65°C to +150°C
Junction Temperature (T <sub>J</sub> )	
CDIP	175°C

# Recommended Operating Conditions

Supply Voltage (V <sub>CC</sub> )	
'AC	2.0V to 6.0V
'ACT	4.5V to 5.5V
Input Voltage (V <sub>I</sub> )	0V to V <sub>CC</sub>
Output Voltage (V <sub>O</sub> )	0V to V <sub>CC</sub>
Operating Temperature (T <sub>A</sub> )	
54AC/ACT	–55°C to +125°C
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
'AC Devices	
$V_{\rm IN}$ from 30% to 70% of $V_{\rm CC}$	
V <sub>CC</sub> @ 3.3V, 4.5V, 5.5V	125 mV/ns
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
'ACT Devices	
V <sub>IN</sub> from 0.8V to 2.0V	
V <sub>CC</sub> @ 4.5V, 5.5V	125 mV/ns
Note 1: Absolute maximum ratings are those values	
to the device may occur. The databook specifications	

CDIP 175°C to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

Symbol	Parameter	V <sub>cc</sub>	54AC $T_A = -55^{\circ}C \text{ to } +125^{\circ}C$	Units	Conditions
		(V)	Guaranteed	-	
			Limits		
VIH	Minimum High Level	3.0	2.1		$V_{OUT} = 0.1V$
	Input Voltage	4.5	3.15	v	or V <sub>CC</sub> – 0.1V
		5.5	3.85		
VIL	Maximum Low Level	3.0	0.9		V <sub>OUT</sub> = 0.1V
	Input Voltage	4.5	1.35	V	or $V_{CC} - 0.1V$
		5.5	1.65		
V <sub>он</sub>	Minimum High Level	3.0	2.9		Ι <sub>ουτ</sub> = –50 μΑ
	Output Voltage	4.5	4.4	V	
		5.5	5.4		
					(Note 2) V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>
		3.0	2.4		I <sub>он</sub> = –12 mA
		4.5	3.7	V	I <sub>он</sub> = –24 mA
		5.5	4.7		I <sub>OH</sub> = -24 mA
V <sub>OL</sub>	Maximum Low Level	3.0	0.1		Ι <sub>ΟUT</sub> = 50 μΑ
	Output Voltage	4.5	0.1	V	
		5.5	0.1		
					(Note 2) V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>
		3.0	0.50		$I_{OL} = 12 \text{ mA}$
		4.5	0.50	V	I <sub>OL</sub> = 24 mA
		5.5	0.50		I <sub>OL</sub> = 24 mA
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	±1.0	μΑ	$V_{I} = V_{CC}, \text{ GND}$
I <sub>OLD</sub>	Minimum Dynamic	5.5	50	mA	V <sub>OLD</sub> = 1.65V Max
I <sub>OHD</sub>	Output Current (Note 3)	5.5	-50	mA	V <sub>OHD</sub> = 3.85V Min

DC Cha	racteristics for 'AC	Family	Devices (Continued)		
			54AC		
Symbol	Parameter	V <sub>cc</sub>	T <sub>A</sub> =	Units	Conditions
		(V)	–55°C to +125°C		
			Guaranteed	]	
			Limits		

160

μA

 $V_{IN} = V_{CC}$ 

or GND

5.5

Note 2: All outputs loaded; thresholds on input associated with output under test.

Maximum Quiescent

Supply Current

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

Note 4: I<sub>IN</sub> and I<sub>CC</sub> @ 3.0V are guaranteed to be less than or equal to the respective limit @ 5.5V V<sub>CC</sub>.

I<sub>CC</sub> for 54AC @ 25°C is identical to 74AC @ 25°C.

 $I_{\rm CC}$ 

## DC Characteristics for 'ACT Family Devices

			54ACT		
Symbol	Parameter	V <sub>cc</sub>	T <sub>A</sub> =	Units	Conditions
		(V)	–55°C to +125°C	- 15	
			Guaranteed		
			Limits	-0-	
VIH	Minimum High Level	4.5	3.0	V	V <sub>OUT</sub> = 0.1V
	Input Voltage (Note 7)	5.5	3.0		or V <sub>CC</sub> – 0.1V
VIL	Maximum Low Level	4.5	0.8	V	V <sub>OUT</sub> = 0.1V
	Input Voltage	5.5	0.8		or V <sub>CC</sub> – 0.1V
V <sub>он</sub>	Minimum High Level	4.5	4.4	V	I <sub>OUT</sub> = -50 μA
	Output Voltage	5.5	5.4		
					(Note 5)
					$V_{IN} = V_{IL} \text{ or } 3.0 \text{V}$
		4.5	3.70	V	I <sub>OH</sub> = –24 mA
		5.5	4.70		I <sub>он</sub> = –24 mA
V <sub>OL</sub>	Maximum Low Level	4.5	0.1	V	I <sub>OUT</sub> = 50 μA
	Output Voltage	5.5	0.1		
					(Note 5)
					$V_{IN} = V_{IL} \text{ or } V_{IH}$
		4.5	0.50	V	I <sub>OL</sub> = 24 mA
		5.5	0.50		I <sub>OL</sub> = 24 mA
I <sub>IN</sub>	Maximum Input	5.5	±1.0	μA	$V_{I} = V_{CC}, GND$
	Leakage Current				
I <sub>CCT</sub>	Maximum	5.5	1.6	mA	$V_{I} = V_{CC} - 2.1V$
	I <sub>CC</sub> /Input				
I <sub>OLD</sub>	Minimum Dynamic	5.5	50	mA	V <sub>OLD</sub> = 1.65V Max
I <sub>онр</sub>	Output Current (Note 6)	5.5	-50	mA	V <sub>OHD</sub> = 3.85V Min
I <sub>cc</sub>	Maximum Quiescent	5.5	80.0	μA	$V_{IN} = V_{CC}$
	Supply Current				or GND

Note 5: All outputs loaded; thresholds on input associated with output under test.

Note 6: Maximum test duration 2.0 ms, one output loaded at a time.

Note 7: For dynamic operation, a V<sub>IH</sub> level between 2.0 and 3.0V may be recognized by this device as a high logic level input. For static operation, a V<sub>IH</sub> ≥ 2.0V will be recognized by this device as a high logic level input. Users are cautioned to verify that this will not affect their system.

			54			
		V <sub>cc</sub> (V)	T <sub>A</sub> =	T <sub>A</sub> = -55°C		
Symbol	Parameter		to +'	Units		
		(Note 8)		C <sub>L</sub> = 50 pF		
			Min	Max		
f <sub>max</sub>	Maximum Clock	3.3	55		MHz	
	Frequency	5.0	90			
t <sub>PLH</sub>	Propagation Delay, CP to Q <sub>n</sub>	3.3	1.0	13.5	ns	
	(PE Input HIGH or LOW)	5.0	1.5	9.5		
t <sub>PHL</sub>	Propagation Delay, CP to Q <sub>n</sub>	3.3	1.0	12.5	ns	
	(PE Input HIGH or LOW)	5.0	1.5	9.5		
t <sub>PLH</sub>	Propagation Delay	3.3	1.0	16.5	ns	
	CP to TC	5.0	1.5	11.0		
t <sub>PHL</sub>	Propagation Delay	3.3	1.0	15.0	ns	
	CP to TC	5.0	1.5	11.0		
t <sub>PLH</sub>	Propagation Delay	3.3	1.0	11.0	ns	
	CET to TC	5.0	1.5	7.5		
t <sub>PHL</sub>	Propagation Delay	3.3	1.0	12.0	ns	
	CET to TC	5.0	1.5	9.0		
bltage Range 5.0	ange 3.3 is 3.3V ±0.3V 0 is 5.0V ±0.5V ating Requirements	3	com			

# AC Operating Requirements

Symbol	Parameter	V <sub>cc</sub> (V)	T <sub>A</sub> = −55°C to +125°C	Units
		(Note 9)	C <sub>L</sub> = 50 pF Guaranteed Minimum	_
ts	Setup Time, HIGH or LOW	3.3	17.0	ns
3	P <sub>n</sub> to CP	5.0	11.0	
t <sub>h</sub>	Hold Time, HIGH or LOW	3.3	-0.5	ns
	P <sub>n</sub> to CP	5.0	0	
t <sub>s</sub>	Setup Time, HIGH or LOW	3.3	17.0	ns
	SR to CP	5.0	12.0	
t <sub>h</sub>	Hold Time, HIGH or LOW	3.3	-0.5	ns
	SR to CP	5.0	0	
t <sub>s</sub>	Setup Time, HIGH or LOW	3.3	16.0	ns
	PE to CP	5.0	9.5	
t <sub>h</sub>	Hold Time, HIGH or LOW	3.3	-0.5	ns
	PE to CP	5.0	0	
t <sub>s</sub>	Setup Time, HIGH or LOW	3.3	8.0	ns
	CEP or CET to CP	5.0	5.5	
t <sub>h</sub>	Hold Time, HIGH or LOW	3.3	0	ns
	CEP or CET to CP	5.0	0.5	
t <sub>w</sub>	Clock Pulse Width (Load)	3.3	5.0	ns
	HIGH or LOW	5.0	5.0	
t <sub>w</sub>	Clock Pulse Width (Count)	3.3	5.0	ns
	HIGH or LOW	5.0	5.0	

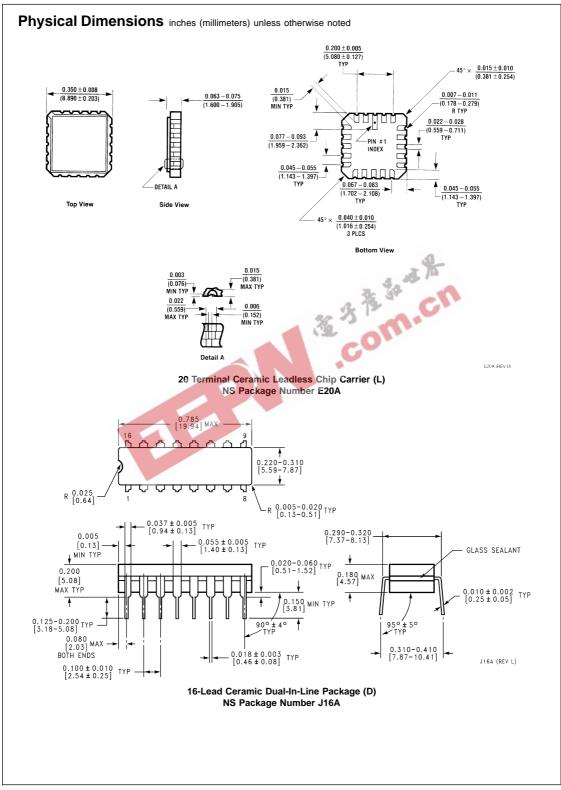
			54ACT		Units
		V <sub>cc</sub>	T <sub>A</sub> = -		
Symbol	Parameter	(V)	to +125°C C <sub>L</sub> = 50 pF		
		(Note 10)			
			Min	Max	
f <sub>max</sub>	Maximum Clock	5.0	90		MHz
	Frequency				
t <sub>PLH</sub>	Propagation Delay, CP to Q <sub>n</sub>	5.0	1.5	10.5	ns
	(PE Input HIGH or LOW)				
t <sub>PHL</sub>	Propagation Delay, CP to Q <sub>n</sub>	5.0	1.5	10.5	ns
	(PE Input HIGH or LOW)				
t <sub>PLH</sub>	Propagation Delay	5.0	1.5	12.5	ns
	CP to TC				
t <sub>PHL</sub>	Propagation Delay	5.0	1.5	13.0	ns
	CP to TC				
t <sub>PLH</sub>	Propagation Delay	5.0	1.5	9.5	ns
	CET to TC		AP		
t <sub>PHL</sub>	Propagation Delay	5.0	1.5 🚜	9.5	ns
	CET to TC	23	C		
-	Range 5.0 is 5.0V ±0.5V ating Requirements	3 COL	n		

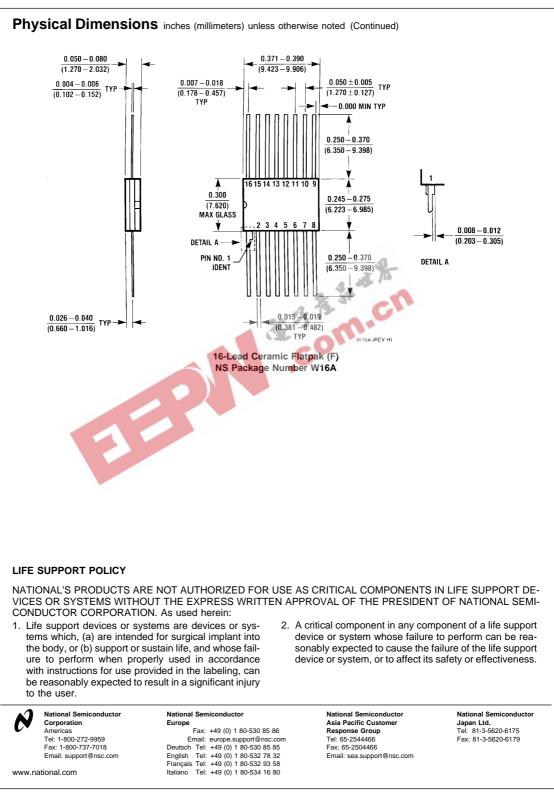
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## AC Operating Requirements

Symbol	Parameter	V <sub>cc</sub> (V)	54ACT T <sub>A</sub> = -55°C to +125°C	Units
	3-	(Note 11)	C <sub>L</sub> = 50 pF Guaranteed Minimum	
t <sub>s</sub>	Setup Time, HIGH or LOW P <sub>n</sub> to CP	5.0	13.5	ns
t <sub>h</sub>	Hold Time, HIGH or LOW P <sub>n</sub> to CP	5.0	0.5	ns
t <sub>s</sub>	Setup Time, HIGH or LOW SR to CP	5.0	13.5	ns
t <sub>h</sub>	Hold Time, HIGH or LOW SR to CP	5.0	0.0	ns
t <sub>s</sub>	Setup Time, HIGH or LOW PE to CP	5.0	11.5	ns
t <sub>h</sub>	Hold Time, HIGH or LOW PE to CP	5.0	0.0	ns
t <sub>s</sub>	Setup Time, HIGH or LOW CEP or CET to CP	5.0	7.0	ns
t <sub>h</sub>	Hold Time, HIGH or LOW CEP or CET to CP	5.0	0.5	ns
t <sub>w</sub>	Clock Pulse Width (Load) HIGH or LOW	5.0	5.0	ns
t <sub>w</sub>	Clock Pulse Width (Count) HIGH or LOW	5.0	5.0	ns







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